

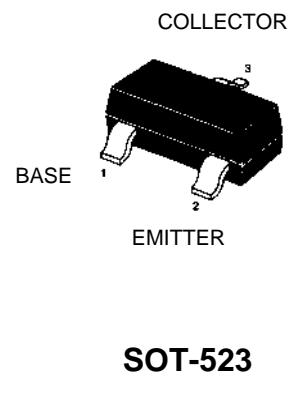


迈拓电子
MAITUO ELECTRONIC

BC817T... TRANSISTOR (NPN)

FEATURE

- For general AF applications
- High collector current
- High current gain
- Low collector-emitter saturation voltage
- Complementary types: BC807T (PNP)



SOT-523

MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	50	V
V_{CEO}	Collector-Emitter Voltage	45	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current -Continuous	0.5	A
P_c	Collector Power Dissipation	0.3	W
T_j	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55-150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	MIN		MAX	UNIT
Collector-base breakdown voltage	V_{CBO}	$I_C= 10\mu\text{A}, I_E=0$	50			V
Collector-emitter breakdown voltage	V_{CEO}	$I_C= 10\text{mA}, I_B=0$	45			V
Emitter-base breakdown voltage	V_{EBO}	$I_E= 1\mu\text{A}, I_C=0$	5			V
Collector cut-off current	I_{CBO}	$V_{CB}= 45 \text{ V}, I_E=0$			0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}= 4\text{V}, I_C=0$			0.1	μA
DC current gain	$h_{FE(1)}$	$V_{CE}= 1\text{V}, I_C= 100\text{mA}$	100		600	
	$h_{FE(2)}$	$V_{CE}= 1\text{V}, I_C= 500\text{mA}$	40			
Collector-emitter saturation voltage	$V_{CE(\text{sat})}$	$I_C= 500\text{mA}, I_B= 50\text{mA}$			0.7	V
Base-emitter saturation voltage	$V_{BE(\text{sat})}$	$I_C= 500\text{mA}, I_B= 50\text{mA}$			1.2	V
Base-emitter voltage	V_{BE}	$V_{CE}= 1 \text{ V}, I_C= 500\text{mA}$			1.2	V
Collector capacitance	C_{ob}	$V_{CB}=10\text{V}, f=1\text{MHz}$		10		pF
Transition frequency	f_T	$V_{CE}= 5 \text{ V}, I_C= 10\text{mA}$ $f=100\text{MHz}$	100			MHz

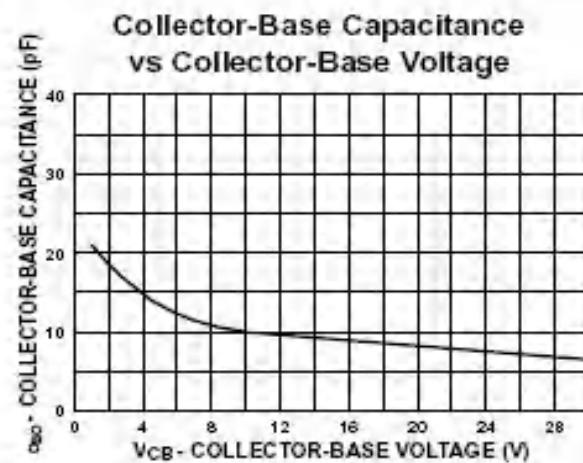
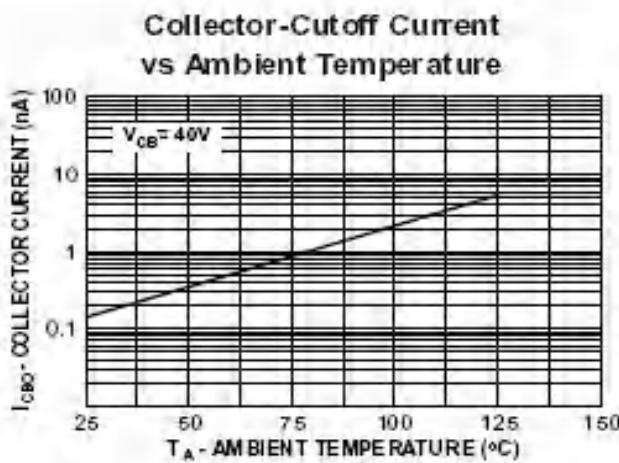
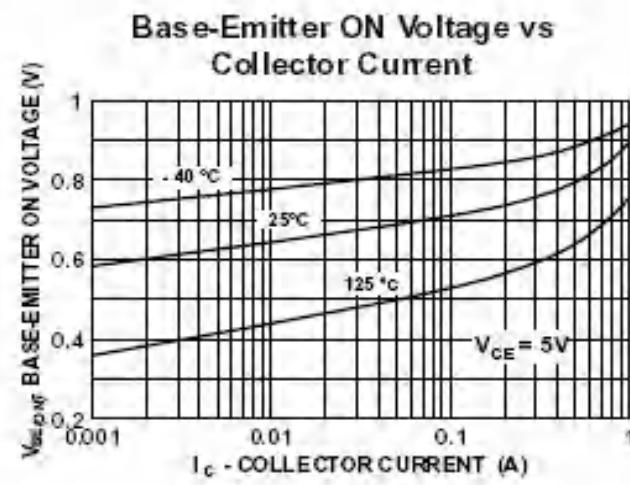
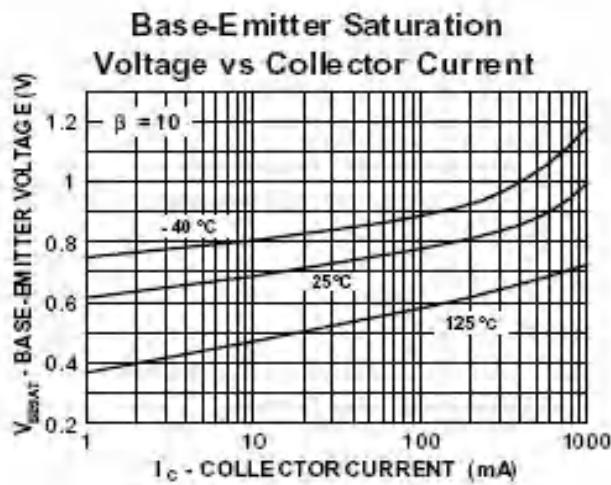
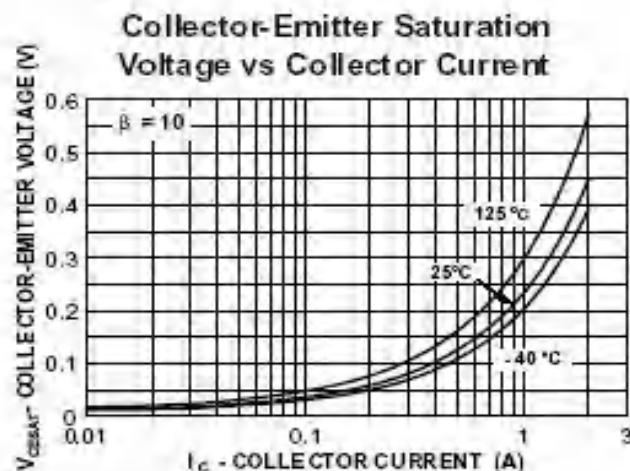
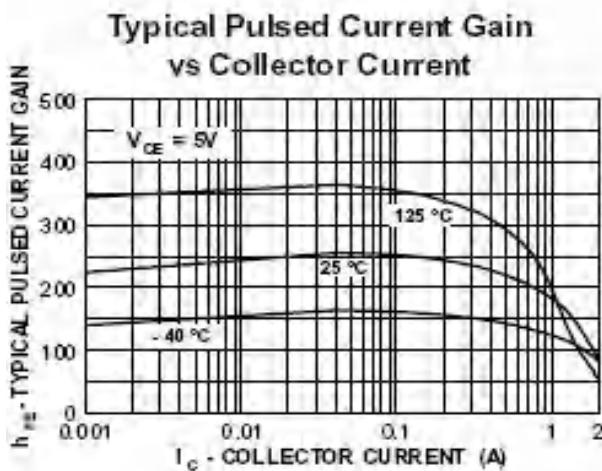
CLASSIFICATION OF $h_{FE}(1)$

Rank	BC817T-16	BC817T-25	BC817T-40
Range	100-250	160-400	250-600
Marking	6A	6B	6C



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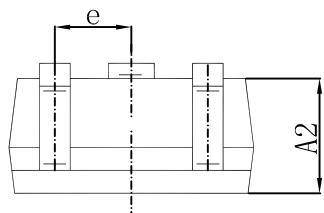
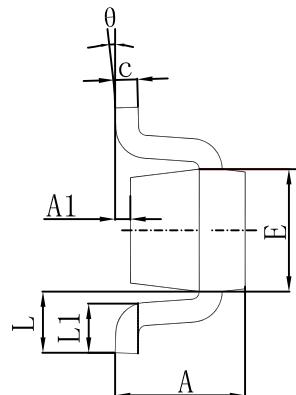
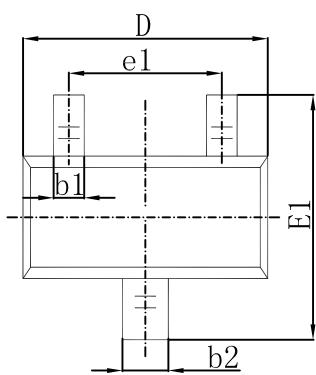
Typical Characteristics





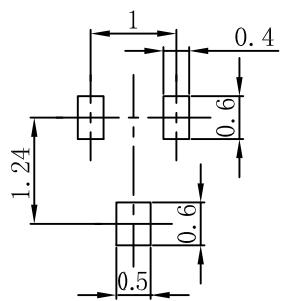
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SOT-523 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
c	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
e	0.500 TYP.		0.020 TYP.	
e1	0.900	1.100	0.035	0.043
L	0.400 REF.		0.016 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

SOT-523 Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.05 mm.
3. The pad layout is for reference purposes only.